

## **Initial Information Data Sheet**

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### **Inventor Information**

Inventor One Given Name: Yasuaki  
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### **Correspondence Information**

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### **Application Information**

Title Line One: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE  
Title Line Two: AND METHOD OF ERASING THE SAME  
Total Drawing Sheets: 18  
Formal Drawings?: Yes  
Application Type: Utility  
Docket Number: 204552022200

### **Representative Information**

Representative Customer Number: 25227

### **Continuity Information**

This application is a:  
> Application One:  
Filing Date:

## **Prior Foreign Application**

Foreign Application One: 2001-013029  
Filing Date: January 22, 2001  
Country: Japan  
Priority Claimed: Yes

2001-013029